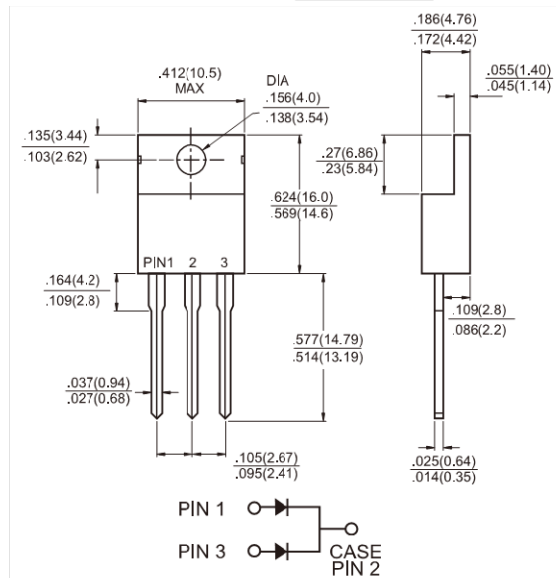


MBR2535CT - MBR25150CT 20.0 AMPS. Schottky Barrier Rectifiers TO-220AB



Features

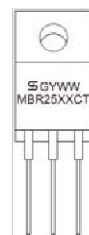
- ◆ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ◆ Metal silicon junction, majority carrier conductor
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Guard-ring for overvoltage protection
- ◆ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case
- ◆ Green compound with suffix "G" on packing code & prefix "G" on datecode



Mechanical Data

- ◆ Cases: JEDEC TO-220AB molded plastic
- ◆ Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- ◆ Polarity: As marked
- ◆ Mounting position: Any
- ◆ Mounting torque: 5 in. - lbs, max
- ◆ Weight: 1.90 grams

Dimensions in inches and (millimeters)



Marking Diagram

- MBR25XXCT = Specific Device Code
- G = Green Compound
- Y = Year
- WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR 2535 CT	MBR 2545 CT	MBR 2550 CT	MBR 2560 CT	MBR 2590 CT	MBR 25100 CT	MBR 25150 CT	Units	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	V	
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	105	V	
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	V	
Maximum Average Forward Rectified Current	$I_{F(AV)}$	25							A	
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	I_{FRM}	25							A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	200							A	
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0	0.5					A		
Maximum Instantaneous Forward Voltage at (Note 2) IF=12.5A, TA=25°C IF=12.5A, TA=125°C IF=25A, TA=25°C IF=25A, TA=125°C	V_F	-	0.75	0.85	0.95	-	-	-	V	
Maximum Instantaneous Reverse Current @ TA=25 °C at Rated DC Blocking Voltage Per Leg @ TA=125 °C	I_R	0.2	0.2	0.1	0.1	15	10	7.5	5	mA mA
Voltage Rate of Change (Rated VR)	dV/dt	10,000							V/us	
Typical Junction Capacitance	Cj	600	460					pF		
Maximum Thermal Resistance Per Leg	$R_{\theta JC}$	1.0							°C/W	
Operating Junction Temperature Range	TJ	- 65 to + 150							°C	
Storage Temperature Range	TSTG	- 65 to + 175							°C	

Note 1: 2.0uS Pulse Width, f=1.0KHz

Note 2: Pulse Test : 300us Pulse Width, 1% Duty Cycle

RATINGS AND CHARACTERISTIC CURVES (MBR2535CT THRU MBR25150CT)

